

SOLID STATE SYNTHESIS OF THE PSEUDO-BINARY OXIDES DOPED WITH V_2O_5 MATERIALS

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ABSTRACT: This paper is focused on the obtaining of materials based on $ZnTa_2O_6$ and $ZnNb_2O_6$ both doped with V_2O_5 , by solid state method. To characterize the obtained materials XRD, SEM/EDAX, AFM and UV-Vis analysis were performed. The morphology of the two materials revealed a rod like shape of the particles with more ordered alignment of particles for the second material. EDAX experiments confirmed the structure and composition of the two compounds. UV-Vis analysis was done and further the band gap for each of the materials was determined, having the following values: 4.03 eV and 4.06 eV.

KEYWORDS: solid state, XRD, SEM/EDAX, AFM, band gap

1. INTRODUCTION

The pseudo-binary oxides $ZnTa_2O_6$ and $ZnNb_2O_6$ are both known as materials which act excellent as photocatalyst [1] or for possessing excellent microwave dielectric properties [2-5]. Until now, it was reported various obtaining methods as molten salt synthesis [2], solid state method [6], coprecipitation [3], hydrothermal [7] and also sol-gel [8-10] method. It was shown that the advantages of using molten salt synthesis is that it could control the form and size of the particle, because solid-state and sol-gel methods are offering sometimes a too dispersed size of particle and too high temperatures might be used in obtaining.

The vanadium oxide, V_2O_5 , is known as a precursor widely used in obtaining materials as: wurtzite, phosphor materials or vanadate glasses, often in combination with ZnO [11-13].

In the present paper, results regarding the obtaining through the solid state synthesis method and characterization of $ZnTa_2O_6$ and of the $ZnNb_2O_6$ materials both doped with V_2O_5 materials are presented.

2. EXPERIMENTAL

1. Solid state synthesis of the $ZnTa_2O_6$ and $ZnNb_2O_6$, both doped with V_2O_5

The materials $ZnTa_2O_6$ and $ZnNb_2O_6$, both doped with V_2O_5 , were obtained through the solid state method. The precursors that were used are: the pseudo-binary oxide $ZnTa_2O_6$ obtained at 1100°C through the solid-state method as it was described in [14], the pseudo-binary oxide $ZnNb_2O_6$ obtained by the same solid-state method and tantalum pentaoxide (V_2O_5) (99, 6 % purity, Sigma).

The obtained mixtures using the molar ratio ($ZnTa_2O_6$)0.9 and (V_2O_5)0.1, ($ZnNb_2O_6$)0.9 and (V_2O_5)0.1 were synthesized in a calcination oven at 600°C for 6 h/each sample. The heating and cooling rate of the oven was 5°C/min.

2. Characterization techniques:

The characterizations have been performed on well crystallized powder samples of materials.

The phase identification of the synthesized powders was performed using X-ray diffraction (XRD) with monochromatic Cu $K\alpha$ ($\lambda = 1.5418 \text{ \AA}$) incident radiation on an X'pert Pro MPD X-ray Diffraction data were obtained for the angular range $2\theta = 10-80^\circ$ using a 0.020 step and the counting time was 5 s.

To determinate the morphology and the particle's dimension of the samples, the field emission-scanning electron microscopy – SEM (Model INSPECT S) and Atomic Force microscopy - AFM (Model Nanosurf® EasyScan 2 Advanced Research) were used. The optical band gap of both materials was calculated by recording the diffuse reflectance

spectrum at room temperature, using a UV-VIS-NIR spectrometer Lambda 950.

3. RESULTS AND DISCUSSIONS

1. Quality determination of pseudo-binary oxides materials using XRD

In figures 1 and 2 are presented the X-ray diffraction spectra of the ZnTa_2O_6 and ZnNb_2O_6 materials doped with V_2O_5 compared with the XRD spectra of the ZnTa_2O_6 respectively ZnNb_2O_6 materials. Also, in these figures the most intense peaks magnified are inserted and it can be observed that the ZnTa_2O_6 doped with V_2O_5 , respectively ZnNb_2O_6 doped with V_2O_5 spectra are shifted to the left, due to the fact that the ionic radii of the dopant (V) is smaller than the ionic radii of the element that V substitutes (Ta respectively Nb).

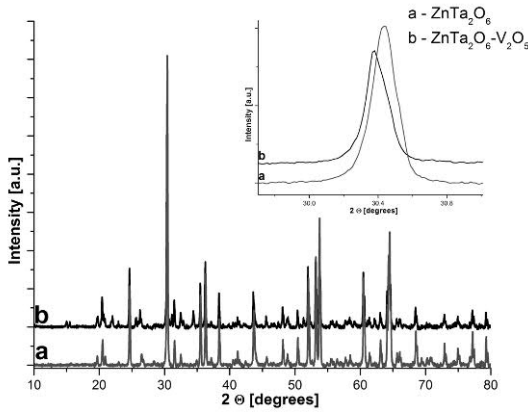


Figure 1. The diffraction spectra of the ZnTa_2O_6 doped with V_2O_5 and ZnTa_2O_6 . In the right upper part of the plot is presented the magnified spectra of the most intense peak.

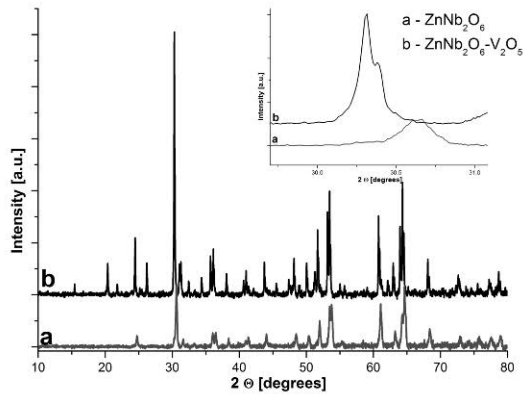


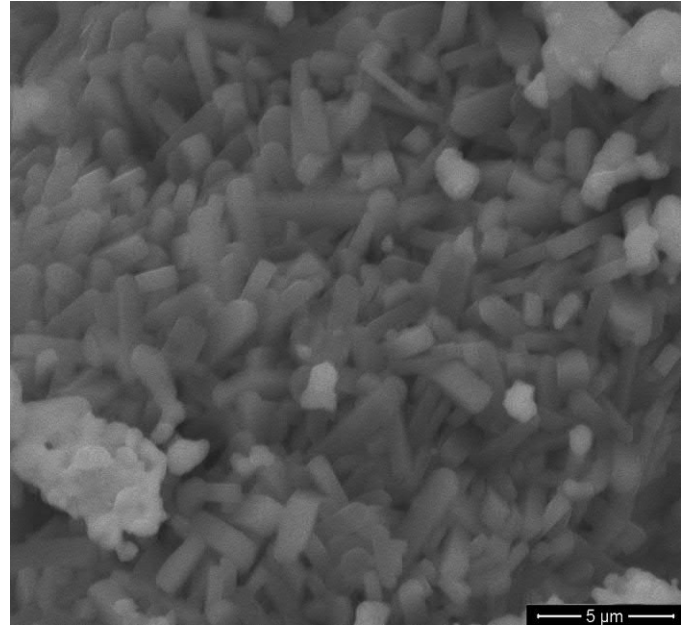
Figure 2. The diffraction spectra of the ZnNb_2O_6 doped with V_2O_5 and ZnNb_2O_6 . In the right upper part of the plot is presented the magnified spectra of the most intense peak.

2. The morphologic and crystallites size study for ZnTa_2O_6 doped with V_2O_5 and ZnNb_2O_6 doped with V_2O_5

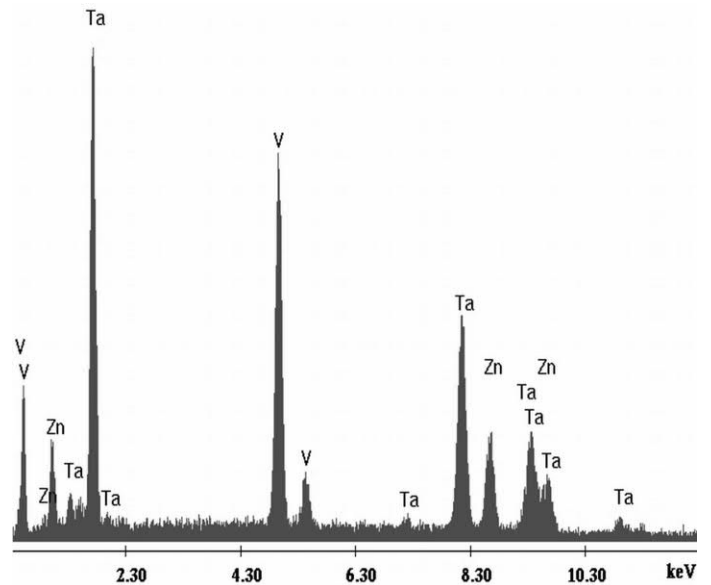
In Figure 3(a), from SEM image, it can be observed that the shape of the particles for ZnTa_2O_6 doped with V_2O_5 is rod like. For ZnNb_2O_6 doped with V_2O_5

(figure 4(a)), the same rod like shape is noticed which confirms the previously reported experiments [2, 6], with the observation that the image reveal smaller rods in a more ordered form, oriented by a direction reporting to the ZnTa_2O_6 doped with V_2O_5 .

From the EDAX images, (figures 3(b) and 4(b)), only the Zn, V, Ta and respectively Nb peaks can be observed which demonstrate the material composition.

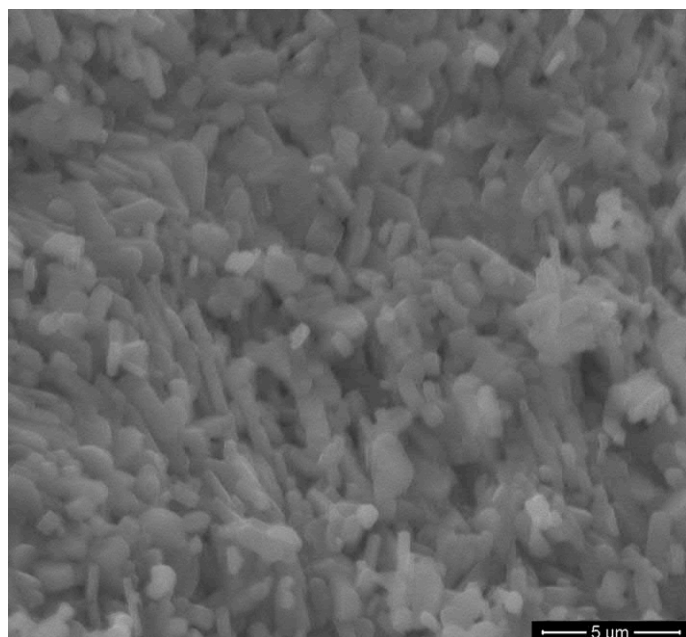


(a)

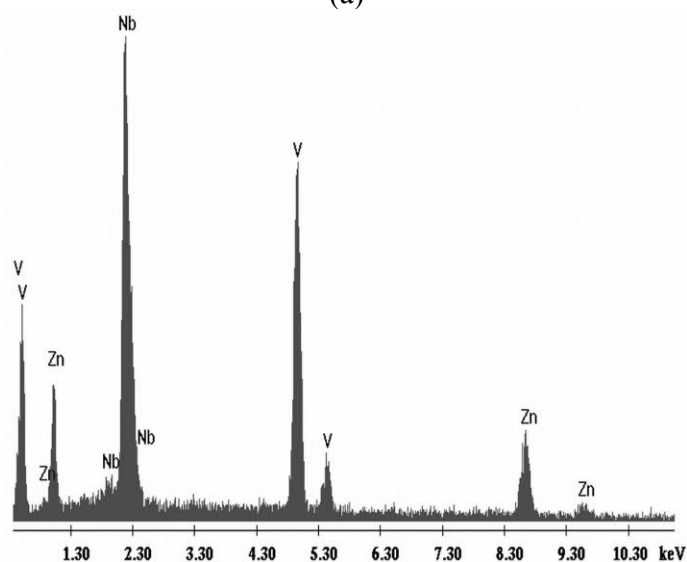


(b)

Figure 3. SEM (a) and EDAX (b) images for ZnTa_2O_6 doped with V_2O_5 obtained at 600°C with a 6 h reaction time



(a)

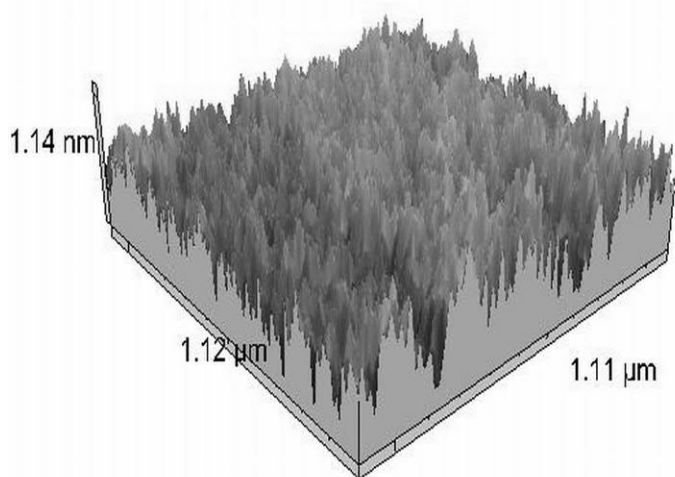


(b)

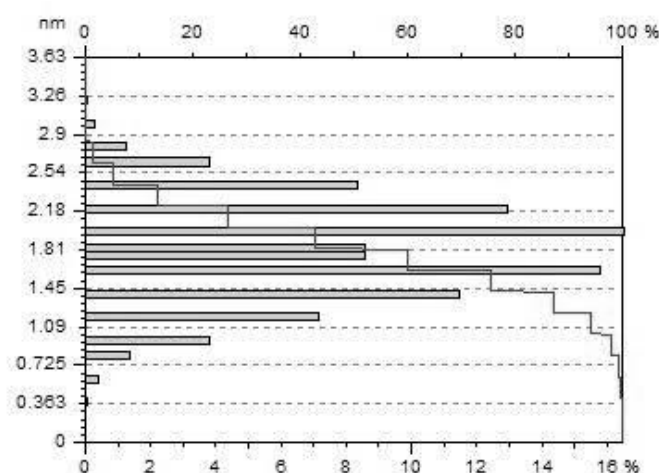
Figure 4. SEM (a) and EDAX (b) images for ZnNb_2O_6 doped with V_2O_5 obtained at 600°C with a 6 h reaction time

To confirm the results obtained from the SEM measurements, AFM measurements were realised in the contact mode on a surface of about $1\mu\text{m} \times 1\mu\text{m}$ for each material. From figure 5 (a) it can be observed the topographical map for ZnTa_2O_6 doped with V_2O_5 and from figure 5(b) the size of the particles which is between 1 and 2.5 nm. From figure 5 (c) it can be seen that the particles are uniformly arranged on the analysed surface.

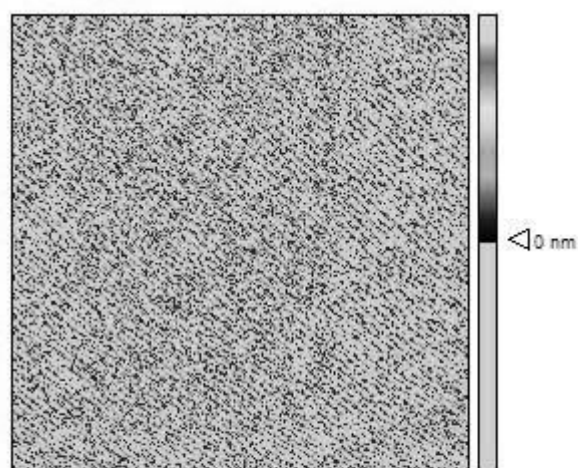
The AFM images of ZnNb_2O_6 doped with V_2O_5 are presented in figure 6. The 3D topographical map of the material in presented in figure 6 (a). From figure 6(b) it was noticed that the particles size is between 2 and 4 nm. Figure 6 (c) shows an uniformly distribution of the particles on the analysed surface.



(a)



(b)

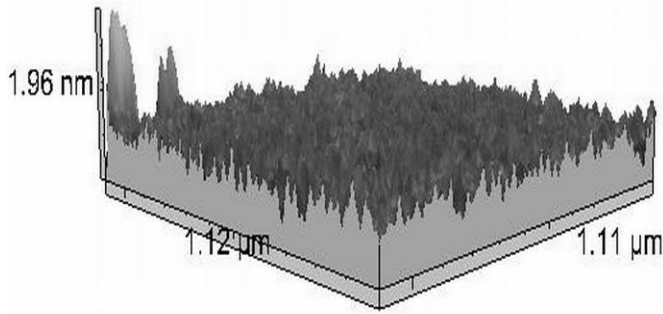


Number of islands	3157
Mean volume of islands	75.8 nm ³
Mean height of islands	0.581 nm
Mean surface of islands	0.000179 μm ²
Mean height / surface ratio	3250 nm/μm ²

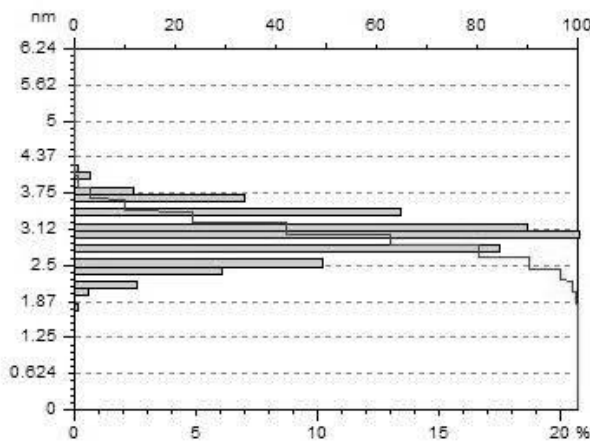
(c)

Figure 5. The AFM images of ZnTa_2O_6 doped with V_2O_5 representing: a) the 3D topographical map; b) Height

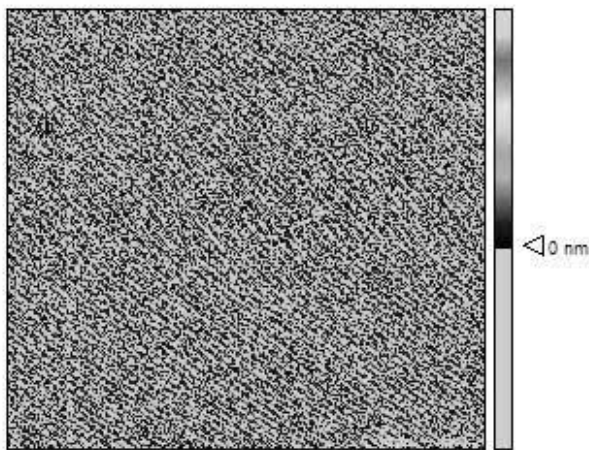
distributions of the particles; c) The particles distribution on the scanned surfaces



(a)



(b)



Number of islands	3179
Mean volume of islands	51.5 nm ³
Mean height of islands	0.46 nm
Mean surface of islands	0.000199 μm ²
Mean height / surface ratio	2316 nm/μm ²

(c)

Figure 6. The AFM images of ZnNb₂O₆ doped with V₂O₅ representing: a) the 3D topographical map; b) Height distributions of the particles; c) The particles distribution on the scanned surfaces

Using the following equations for the average surface roughness and the root mean squared surface roughness's calculations [15]:

$$S_a = \frac{1}{mn} \sum_{j=1}^n \sum_{i=1}^m |z_{ij}| \quad (1)$$

$$S_q = \sqrt{\frac{1}{mn} \sum_{i=1}^m \sum_{j=1}^n z^2(x_i, y_j)} \quad (2)$$

S_a and S_q were determined for an area $A=1.312 \mu m^2$ (see Table 1). In equations (1) and (2) m and n represent the number of the particles on x and y axis, with z -the medium high of the particles, x_k and y_l represent the minimum and the maximum deviations of the particles related to the medium value.

Table 1. The calculated roughness for the ZnTa₂O₆ and ZnNb₂O₆ doped with V₂O₅ materials

Material	S_a	S_q
ZnTa ₂ O ₆ doped with V ₂ O ₅	0.1 nm	0.18 nm
ZnNb ₂ O ₆ doped with V ₂ O ₅	0.096 nm	0.17 nm

3.3. The optical properties of the ZnTa₂O₆ and ZnNb₂O₆ doped with V₂O₅ materials

Using the Kubelka-Munk equations [16, 17], from the reflectance spectrum, the absorbance was calculated (Figure 7). Using the absorbance spectra, the band gap was determined. $\{(k/s)hv\}^2$ versus hv plot was inserted in figure 7.

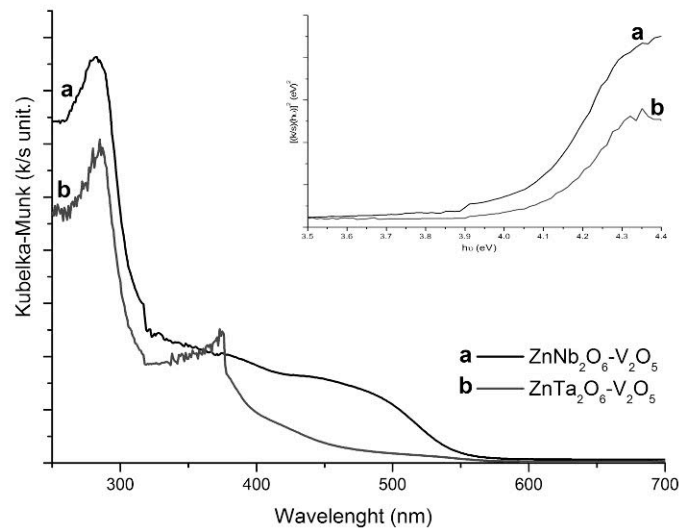


Figure 7. The absorbance spectrum of: ZnTa₂O₆ doped with

V₂O₅ and ZnNb₂O₆ doped with V₂O₅ . vs. hv
(energy was inserted for: ZnTa₂O₆ doped with V₂O₅ and ZnNb₂O₆ doped with V₂O₅)

For ZnTa₂O₆ doped with V₂O₅, the band gap value was found to be 4.06 eV and respectively, 4.03 eV for ZnNb₂O₆ doped with V₂O₅. For this second

material was reported in the literature [10] the same value for the band gap (4.0eV).

4. CONCLUSIONS

This paper is devoted to the obtaining of ZnTa_2O_6 and of ZnNb_2O_6 both doped with V_2O_5 through the solid state method at 600°C . XRD experiments show that both materials were formed, the most intense peaks being shifted to left, due to the smaller ionic radii of the dopant V ions which substitute the Ta respectively the Nb ions in the pseudo-binary oxides materials: ZnTa_2O_6 and ZnNb_2O_6 . SEM/EDAX images revealed in both cases a rod like shape of the particles, which for the second analysed material are aligned according with a direction. The morphology and the size of particles were confirmed by the AFM measurements. UV-Vis analyses were made and further it was calculated the band gap for each of the materials, for ZnTa_2O_6 doped with V_2O_5 , the band gap value was found to be 4.06 eV and respectively, 4.03 eV for ZnNb_2O_6 doped with V_2O_5 .

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6. REFERENCES

1. Ding Z., Wu W., Liang S., Zheng H., Wu L., Selective-syntheses, characterizations and photocatalytic activities of nanocrystalline ZnTa_2O_6 photocatalysts, *Mat. Lett.*, Vol. 65, pp. 1598- 1600, (2011).
2. Guo, L., Dai, J., Tian, J., Zhu, Z., He, T., Molten salt synthesis of ZnNb_2O_6 powder, *Mater. Res. Bull.*, Vol. 42, pp. 2013–2016, (2007).
3. Deshpande, V. V., Patil, M. M., Navale, S. C., Ravi, V., A coprecipitation technique to prepare

- ZnNb_2O_6 powders, *Bull. Mater. Sci.*, Vol. 28, pp. 205– 207, (2005).
4. Hsiao, Y.-J., Fang, T.-H., Ji, L.-W., Synthesis and luminescent properties of ZnNb_2O_6 nanocrystals for solar cell, *Mater. Lett.*, Vol.64, pp. 2563–2565, (2010).
5. Guo, L., Dai, J., Tian, J., He, T., Synthesis of ZnNb_2O_6 powder with rod-like particle morphologies, *Ceram. Int.*, Vol.34, pp. 1783–1785, (2008).
6. Feng, G., Jiaji, L., Rongzi, H., Zhen, L., Changsheng, T., Microstructure and dielectric properties of low temperature sintered ZnNb_2O_6 microwave ceramics, *Ceram. Int.*, Vol.35, pp. 2687–2692, (2009).
7. Dai, J., Zhang, C., Shi, L., Song, W., Wu, P., Huang, X., Low-temperature synthesis of ZnNb_2O_6 powders via hydrothermal method, *Ceram. Int.*, Vol. 38, pp. 1211–1214, (2012).
8. Hsiao, Y.-J., Fang, T.-H., Ji, L.-W., Synthesis and luminescent properties of ZnNb_2O_6 nanocrystals for solar cell, *Mater. Lett.*, Vol. 64, pp. 2563 – 2565, (2010).
9. Hsu, C.-H., Yang, P.-C., Yang, H.-W., Yan, S.-F.,Tung H. H., Study and fabrication of ZnNb_2O_6 thin films by sol–gel method, *Thin Sol. Films*, Vol. 519, pp. 5030–5032, (2011).
10. Wu, W., Liang, S., Ding, Z., Zheng, H., Wu, L., Low temperature synthesis of nanosized ZnNb_2O_6 photocatalysts by a citrate complex method, *J. Sol-Gel Sci. Technol.*, Vol. 61, pp. 570–576, (2012).
11. Li, T., Luo, J., Honda, Z., Fukuda, T., Kamata, N., Sintering Condition and Optical Properties of $\text{Zn}_3\text{V}_2\text{O}_8$ Phosphor, *Adv. Math. Phys. Chem.*, Vol. 2, pp. 173-177, (2012).
12. Lopez-Calzada, G., Pancardo-Rodriguez, I., Carmona-Rodriguez, J., Zayas, M. E., Rodriguez- Melgarejo, F., Martinez-Juarez, J., Juarez-Diaz, G., Zelaya-Angel, O., Portillo-Moreno, O., Jimenez- Sandoval, S. J., Lozada-Morales, R., Local order effects on the photoluminescence of Er^{3+} in a novel vitreous matrix of the $\text{CdO-ZnO-V}_2\text{O}_5$ system and manifolds in $\text{Zn}_x\text{Al}_{2-x}\text{O}_3$ micro crystalline aggregates, *Opt. Mater.*, Vol. 32, pp. 1090- 1094, (2010).
13. Chen, Z., Chen, D., Lv, P., Yan, F., Zhan, Z., Li, B. Huang, F., Liang, J., Subsolidus phase relationships in the system $\text{ZnO-V}_2\text{O}_5\text{-WO}_3$

- research on suitable flux for ZnO crystal growth, *J. Alloy. Compd.*, Vol. 476, pp. 241-244, (2009).
14. Birdeanu, M., Birdeanu, A.-V., Fagadar- Cosma, E., Enache, C., Miron, I., Grozescu, I., Structural, morphological, optical and thermal properties of the ZnTa_2O_6 nanomaterials obtained by solid – state method, *Digest J. Nanomater. Bios.*, Vol. 8, pp. 263 – 272, (2013).
 15. Johnson, D., Hilal, N., Characterisation and quantification of membrane surface properties using atomic force microscopy: A comprehensive review, *Desalination*, Vol. 356, pp. 149- 164, (2015).
 16. Kubelka, P., Munk F. Ein Beitrag zur Optik der Farban-striche. *Zh Tekh Fiz.*, Vol. 12, pp. 593-607, (1931).
 17. Kubelka, P., New contribution to the optics of intensely light-scattering materials. Part I, *J. Opt Soc. Am.*, Vol. 38, pp. 448-57, (1948).